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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/630,680	07/31/2003	Yasuo Suda	03500.016294.1	7671
5514	7590 03/04/2004		EXAMINER	
FITZPATRICK CELLA HARPER & SCINTO			ANYA, IGWE U	
	FELLER PLAZA K, NY 10112		ART UNIT	PAPER NUMBER
7,2,, 1010	,		2825	
			DATE MAILED: 03/04/200	4

Please find below and/or attached an Office communication concerning this application or proceeding.

				My		
		Application No.	Applicant(s)			
		10/630,680	SUDA, YASUO			
	Office Action Summary	Examiner	Art Unit			
		Igwe U. Anya	2825			
Period f	The MAILING DATE of this communicat or Reply	ion appears on the cover sheet w	ith the correspondence address			
A SH THE - Exte after - If the - If NO - Failt Any	IORTENED STATUTORY PERIOD FOR MAILING DATE OF THIS COMMUNICA ensions of time may be available under the provisions of 37 of SIX (6) MONTHS from the mailing date of this communic experiod for reply specified above is less than thirty (30) data of period for reply is specified above, the maximum statutor under the provided period for reply will, reply received by the Office later than three months after the patent term adjustment. See 37 CFR 1.704(b).	TION. 'CFR 1.136(a). In no event, however, may a ation. ys, a reply within the statutory minimum of thi y period will apply and will expire SIX (6) MOI by statute, cause the application to become A	reply be timely filed rty (30) days will be considered timely. NTHS from the mailing date of this communion BANDONED (35 U.S.C. § 133).	cation.		
Status						
1)⊠	Responsive to communication(s) filed o	n <u>31 <i>July 2003</i></u> .				
2a) <u></u> □	This action is FINAL. 2b)[☑ This action is non-final.				
3)	Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.					
Disposit	ion of Claims					
5)□ 6)⊠ 7)□	Claim(s) 3-13 is/are pending in the appl 4a) Of the above claim(s) is/are v Claim(s) is/are allowed. Claim(s) 3-13 is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction	vithdrawn from consideration.				
Applicat	ion Papers					
10)⊠	The specification is objected to by the Ex The drawing(s) filed on <u>31 July 2003</u> is/a Applicant may not request that any objection Replacement drawing sheet(s) including the The oath or declaration is objected to by	are: a)⊠ accepted or b)□ obje n to the drawing(s) be held in abeya correction is required if the drawing	nce. See 37 CFR 1.85(a). g(s) is objected to. See 37 CFR 1.1			
Priority	under 35 U.S.C. § 119					
a)	Acknowledgment is made of a claim for All b) Some * c) None of: 1. Certified copies of the priority doc 2. Certified copies of the priority doc 3. Copies of the certified copies of the application from the International See the attached detailed Office action for	cuments have been received. cuments have been received in the ne priority documents have been Bureau (PCT Rule 17.2(a)).	Application No. <u>10/009,960</u> . In received in this National Stage	•		
Attachmer	nt(s) ce of References Cited (PTO-892)	4) Interview	Summary (PTO-413)			
2) 🔲 Notio 3) 🛭 Infor	ce of References Cited (F10-692) ce of Draftsperson's Patent Drawing Review (PTO- mation Disclosure Statement(s) (PTO-1449 or PTC er No(s)/Mail Date <u>07312003</u> .	948) Paper No	(s)/Mail Date Informal Patent Application (PTO-152)			

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DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 3 5 are rejected under 35 U.S.C. 102(b) as being anticipated by DiFazio et al. (US Patent 6059188)
- 3. DiFazio et al. teach a semiconductor manufacturing method comprising, bonding a first rectangular wafer (1200) having a plurality lenses (1201) to a second rectangular wafer substrate (1204) having light reception elements (1206) using spacers (1203), and cutting the substrates at a position where the spacer is disposed under the first substrate (col. 8 lines 3 26).

Claim Rejections - 35 USC § 103

- 4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 5. Claims 6 13 are rejected under 35 U.S.C. 103(a) as being unpatentable over D;Fazio 6,059,188 Bennien (US Patent 4732559) in view Komatsu et al. (US Patent 6613443).

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6. DiFazio et al. teach the features previously outlined but lack holding a semiconductor substrate on a base to remove warp and bonding an opposing substrate with a size adjusted according to the warp of the semiconductor substrate to the semiconductor substrate, and bonding a plurality of opposing substrate with a gap corresponding to the size of the warp of the semiconductor substrate to the semiconductor substrate.

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- 7. However, Komatsu et al. teach holding a semiconductor substrate (2) on a base (4) to remove warp and bonding an opposing substrate (3) with a size (fig. 2) adjusted according to the warp of the semiconductor substrate unto the semiconductor substrate (col. 24 lines 1 13). The size adjustment comprising a gap (fig. 2 element L) corresponding to the size of the warp of the semiconductor substrate (col. 33 lines 18 28).
- 8. Therefore, it would have been obvious to one of ordinary skill in the art at the time the invention was made to incorporate the teachings of Komatsu et al. into the DiFazio et al. reference to a fabricate an optical substrate with a flat surface.
- 9. Prior art considered, but not used in the rejection include Bennion (US Patent 4732599), Feldman et al. (US Patent 5886971), and Tsubota et al. (US Patent 5677749).
- 10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Igwe U. Anya whose telephone number is (751) 272-1887. The examiner can normally be reached on M F 8:30am 5:00pm.

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If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Matthew S. Smith can be reached on (751) 272-1907. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Igwe U. Anya Examiner Art Unit 2825

IA

February 10, 2004

MATTHEW SMITH SUPERVISORY PATENT EXAMINER TECHNOLOGY CENTER 2800